NSN 5961-01-122-7176

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-122-7176 **Inclosure Material:** Metal **Overall Length:** 2.577 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 700.0 repetitive peak off-state voltage and 700.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 110.00 amperes forward current, average of standard range **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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